

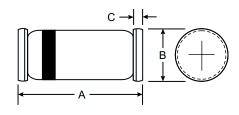
# SURFACE MOUNT FAST SWITCHING DIODE

### Features

- Fast Switching
- High Reliability
- High Conductance

#### **Mechanical Data**

- Case: MiniMELF, Glass
- Terminals: Solderable per MIL-STD-202, Method 208
- Marking: Cathode Band Only
- Polarity: Cathode Band
- Weight: 0.05 grams (approx.)



MiniMELF						
Dim	Min	Max				
Α	3.30	3.70				
В	1.30	1.60				
С	0.28	0.50				
All Dimensions in mm						

# Maximum Ratings @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	LL4151	Unit	
Non-Repetitive Peak Reverse Voltage @ 5.0µA	V <sub>RM</sub>	75	V	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	50	V	
RMS Reverse Voltage	V <sub>R(RMS)</sub>	35	V	
Forward Continuous Current (Note 1)	I <sub>FM</sub>	300	mA	
Average Rectified Output Current (Note 1)	Ι <sub>Ο</sub>	150	mA	
Repetitive Peak Forward Current (Note 1)	I <sub>FRM</sub>	400	mA	
$\begin{array}{llllllllllllllllllllllllllllllllllll$	IFSM	0.5 2.0	А	
Power Dissipation (Note 1)	Pd	500	mW	
Thermal Resistance, Junction to Ambient Air (Note 1)	R <sub>0JA</sub>	300	K/W	
Operating and Storage Temperature Range	Tj, T <sub>STG</sub>	-65 to +175	°C	

## **Electrical Characteristics** @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
Maximum Forward Voltage Drop	V <sub>FM</sub>		1.0	V	$I_F = 50 \text{mA}$
Maximum Peak Reverse Current	I <sub>RM</sub>		50	nA	V <sub>R</sub> = 50V
Junction Capacitance	Cj		2.0	pF	V <sub>R</sub> = 0V, f = 1.0MHz
Reverse Recovery Time	t <sub>rr</sub>	—	4.0	ns	$\label{eq:lf} \begin{array}{l} I_F = I_R = 10 m A, \\ I_{rr} = 0.1 \ x \ I_R, \ R_L = 100 \Omega \end{array}$

Note: 1. Valid provided that electrodes are kept at ambient temperature.